BCD-to-Seven-Segment Decoders/Drivers

The SN74LS247 is a BCD-to-Seven-Segment Decoder/Drivers.

The LS247 composes the \Box and \Box with the tails. The LS247 has active-low outputs for direct drive of indicators.

The LS247 features a lamp test input and have full ripple-blanking input/output controls. An automatic leading and/or trailing-edge zero-blanking control (RBI and RBO) is incorporated and an overriding blanking input (BI) is contained which may be used to control the lamp intensity by pulsing or to inhibit the output's lamp test may be performed at any time when the BI/RBO node is at high level. Segment identification and resultant displays are shown below. Display pattern for BCD input counts above 9 are unique symbols to authenticate input conditions.

- Open-Collector Outputs Drive Indicators Directly
- Lamp-Test Provision
- Leading/Trailing Zero Suppression

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
ІОН	Output Current – High BI/RBO			-50	μΑ
l _{OL}	Output Current – Low BI/RBO			3.2	mA
V _{O(off)}	Off–State Output Voltage a – g			15	V
I _{O(on)}	On–State Output Current a – g			24	mA



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LOW POWER SCHOTTKY



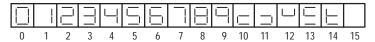
N SUFFIX CASE 648



SOIC D SUFFIX CASE 751B

ORDERING INFORMATION

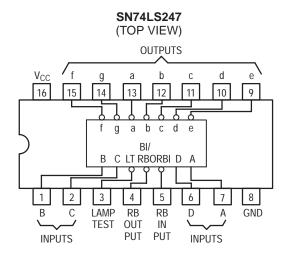
Device	Package	Shipping
SN74LS247N	16 Pin DIP	2000 Units/Box
SN74LS247D	16 Pin	2500/Tape & Reel



NUMERICAL DESIGNATIONS AND RESULTANT DISPLAYS



SEGMENT IDENTIFICATION

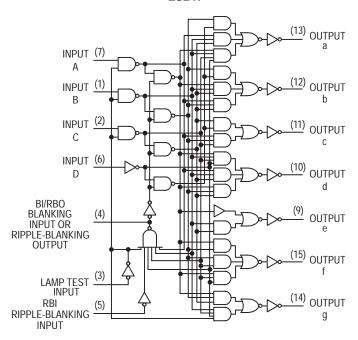


CIRCUIT FEATURES LAMP INTENSITY MODULATION CAPABILITY

		DRIVER OUTF	PUTS		TYPICAL
TYPE	ACTIVE LEVEL	OUTPUT CONFIGURATION	SINK CURRENT	MAX VOLTAGE	POWER DISSIPATION
SN74LS247	low	open-collector	24 mA	15 V	35 mW

LOGIC DIAGRAM

LS247



LS247 **FUNCTION TABLE**

DECIMAL OR			INP	UTS			BI/RBO [†]			О	UTPUT	s			NOTE
FUNCTION	Ľ	RBI	D	С	В	Α	BUILDO	а	b	С	d	е	f	g	NOTE
0	Н	Н	L	L	L	L	Н	ON	ON	ON	ON	ON	ON	OFF	
1	Н	X	L	L	L	Н	Н	OFF	ON	ON	OFF	OFF	OFF	OFF	
2	Н	X	L	L	Н	L	Н	ON	ON	OFF	ON	ON	OFF	ON	
3	Н	X	L	L	Н	Н	Н	ON	ON	ON	ON	OFF	OFF	ON	
4	Н	Х	L	Н	L	L	Н	OFF	ON	ON	OFF	OFF	ON	ON	
5	Н	X	L	Н	L	Н	Н	ON	OFF	ON	ON	OFF	ON	ON	
6	Н	X	L	Н	Н	L	Н	ON	OFF	ON	ON	ON	ON	ON	
7	Н	X	L	Н	Н	Н	Н	ON	ON	ON	OFF	OFF	OFF	OFF	1
8	Н	Х	Н	L	L	L	Н	ON	ON	ON	ON	ON	ON	ON	
9	Н	X	Н	L	L	Н	Н	ON	ON	ON	ON	OFF	ON	ON	
10	Н	X	Н	L	Н	L	Н	OFF	OFF	OFF	ON	ON	OFF	ON	
11	Н	Х	Н	L	Н	Н	Н	OFF	OFF	ON	ON	OFF	OFF	ON	
12	Н	Х	Н	Н	L	L	Н	OFF	ON	OFF	OFF	OFF	ON	ON	
13	Н	X	Н	Н	L	Н	Н	ON	OFF	OFF	ON	OFF	ON	ON	
14	Н	X	Н	Н	Н	L	Н	OFF	OFF	OFF	ON	ON	ON	ON	
15	Н	Х	Н	Н	Н	Н	Н	OFF	OFF	OFF	OFF	OFF	OFF	OFF	
BI	Χ	Х	Х	Χ	Χ	Х	L	OFF	OFF	OFF	OFF	OFF	OFF	OFF	2
RBI	Н	L	L	L	L	L	L	OFF	OFF	OFF	OFF	OFF	OFF	OFF	3
LT	L	X	Χ	Χ	Χ	Χ	Н	ON	ON	ON	ON	ON	ON	ON	4

H = HIGH Level, L = LOW Level, X = Irrelevant

NOTES: 1. The blanking input (BI) must be open or held at a high logic level when output functions 0 through 15 are desired. The ripple-blanking input (RBI) must be open or high if blanking of a decimal zero is not desired.

De open or nign ir blanking or a decimal zero is not desired.

2. When a low logic level is applied directly to the blanking input (BI), all segment outputs are off regardless of the level of any other input.

3. When ripple-blanking input (RBI) and inputs A, B, C, and D are at a low level with the lamp test input high, all segment outputs go off and the ripple-blanking output (RBO) goes to a low level (response condition).

4. When the blanking input/ripple blanking output (BI/RBO) is open or held high and a low is applied to the lamp-test input, all segment outputs are on.

† BI/RBO is wire-AND logic serving as blanking input (BI) and/or ripple-blanking output (RBO).

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

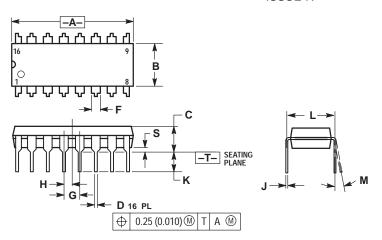
			Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions	
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs		
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Inpu All Inputs	t LOW Voltage for	
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} =	–18 mA	
V _{OH}	Output HIGH Voltage BI/RBO	2.4	4.2		V	$V_{CC} = MIN, I_{OH} =$ or V_{IL} per Truth T		
V	Output LOW Voltage		0.25	0.4	٧	I _{OL} = 1.6 mA	$V_{CC} = V_{CC} MIN,$ $V_{IN} = V_{IL} \text{ or } V_{IH}$	
V _{OL}	BI/RBO		0.35	0.5	٧	I _{OL} = 3.2 mA	per Truth Table	
I _{O(off)}	Off-State Output Current a-g			250	μΑ	V _{CC} = MAX, V _{IH} = 2.0 V, V _{O(off)} = 15 V, V _{IL} = MAX		
V	On-State Output Voltage		0.25	0.4	V	$I_{O(on)} = 12 \text{ mA}$	$V_{CC} = MIN, V_{IH} = 2.0 V,$	
V _{O(on)}	a-g		0.35	0.5	V	I _{O(on)} = 24 mA	V _{IL} per Truth Table	
l	Input HIGH Current			20	μΑ	V _{CC} = MAX, V _{IN}	= 2.7 V	
1 _{IH}	Input nigh current			0.1	mA	V _{CC} = MAX, V _{IN}	= 7.0 V	
I _{IL}	Input LOW Current Any Input, except BI/RBO			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V		
	BI/RBO			-1.2				
I _{OS}	Short Circuit Current BI/RBO (Note 1)	-0.3		-2.0	mA	V _{CC} = MAX		
Icc	Power Supply Current		7.0	13	mA	V _{CC} = MAX		

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _{PLH} t _{PHL}	Turn-Off Time from A Input Turn-On Time from A Input			100 100	ns	C _L = 15 pF,
t _{PHL} t _{PLH}	Turn-Off Time from RBI Input Turn-On Time from RBI Input			100 100	ns	$R_L = 665 \Omega$

PACKAGE DIMENSIONS

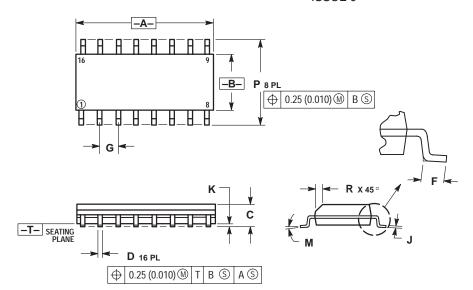
N SUFFIX PLASTIC PACKAGE CASE 648-08 ISSUE R



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
 5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.740	0.770	18.80	19.55	
В	0.250	0.270	6.35	6.85	
С	0.145	0.175	3.69	4.44	
D	0.015	0.021	0.39	0.53	
F	0.040	0.70	1.02	1.77	
G	0.100	BSC	2.54 BSC		
Н	0.050	BSC	1.27 BSC		
J	0.008	0.015	0.21	0.38	
K	0.110	0.130	2.80	3.30	
L	0.295	0.305	7.50	7.74	
М	0°	10 °	0°	10 °	
S	0.020	0.040	0.51	1.01	

D SUFFIX PLASTIC SOIC PACKAGE CASE 751B-05 ISSUE J



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INCHES			
DIM	MIN	MAX	MIN	MAX		
Α	9.80	10.00	0.386	0.393		
В	3.80	4.00	0.150	0.157		
С	1.35	1.75	0.054	0.068		
D	0.35	0.49	0.014	0.019		
F	0.40	1.25	0.016	0.049		
G	1.27	BSC	0.050 BSC			
J	0.19	0.25	0.008	0.009		
K	0.10	0.25	0.004	0.009		
M	0 °	7°	0°	7°		
Р	5.80	6.20	0.229	0.244		
R	0.25	0.50	0.010	0.019		

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